

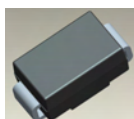
1.0A HIGH VOLTAGE SCHOTTKY BARRIER RECTIFIER

Features

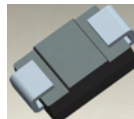
- Guard Ring Die Construction for Transient Protection
- Ideally Suited for Automated Assembly
- Low Power Loss, High Efficiency
- Surge Overload Rating to 50A Peak
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Application
- High Temperature Soldering: 260°C/10 Second at Terminal
- **Lead Free Finish, RoHS Compliant (Note 1)**
- **Green Molding Compound (No Halogen and Antimony) (Note 2)**

Mechanical Data

- Case: SMB
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208 
- Polarity: Cathode Band or Cathode Notch
- Weight: 0.093 grams (approximate)



Top View



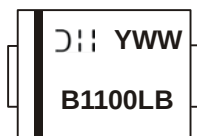
Bottom View

Ordering Information (Note 3)

Part Number	Case	Packaging
B1100LB-13-F	SMB	3000/Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see EU Directive 2002/95/EC Annex Notes.
 2. Product manufactured with Data Code 0924 (week 24, 2009) and newer are built with Green Molding Compound.
 3. For packaging details, go to our website at <http://www.diodes.com>.

Marking Information



B1100LB = Product type marking code
 ⌋⌋⌋ = Manufacturers' code marking
 YWW = Date code marking
 Y = Last digit of year (ex: 02 for 2002)
 WW = Week code (01 to 53)

Note: Device has a cathode band and may also have a cathode notch.

Maximum Ratings @T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.
 For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	100	V
Working Peak Reverse Voltage	V _{RWM}		
DC Blocking Voltage @ I _R = 0.5mA	V _R		
RMS Reverse Voltage	V _{R(RMS)}	70	V
Average Rectified Output Current @ T _T = 120°C	I _O	1.0	A
@ T _T = 100°C		2.0	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load	I _{FSM}	50	A

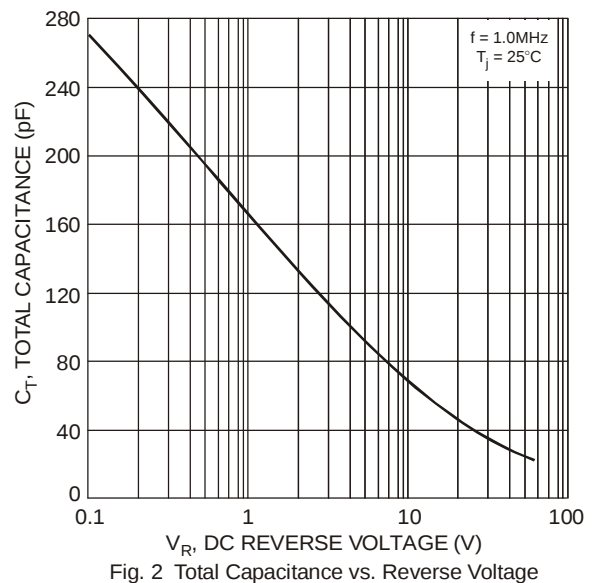
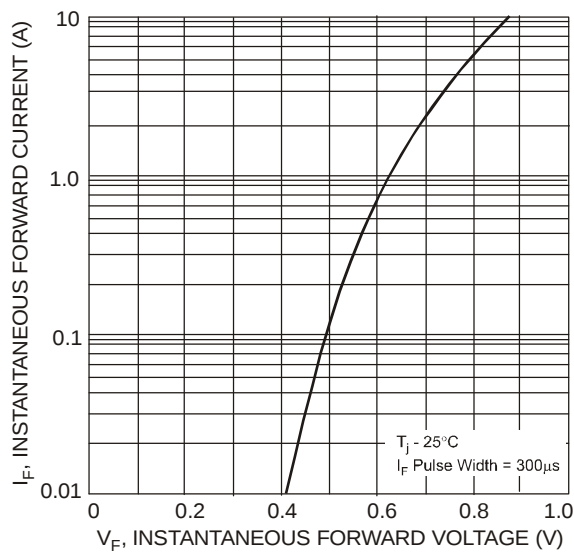
Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Terminal (Note 4)	R _{θJT}	22	°C/W
Operating and Storage Temperature Range (Note 5)	T _J , T _{STG}	-65 to +175	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Forward Voltage Drop	V _F	-	-	0.75	V	I _F = 1.0A, T _A = 25°C
Leakage Current (Note 6)	I _R	-	-	0.5 5.0	mA	V _R = 100V, T _A = 25°C V _R = 100V, T _A = 100°C
Total Capacitance	C _T	-	-	100	pF	V _R = 4V, f = 1MHz

- Notes:
4. Valid provided that terminals are kept at ambient temperature.
 5. The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.
 6. Short duration pulse test used to minimize self-heating effect.



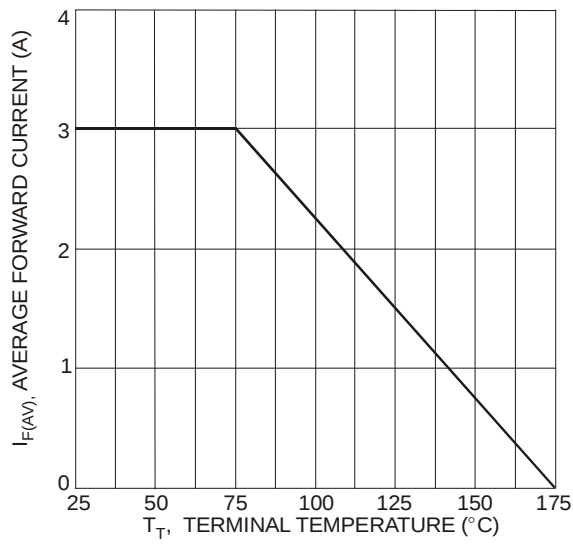


Fig. 3 Forward Current Derating Curve

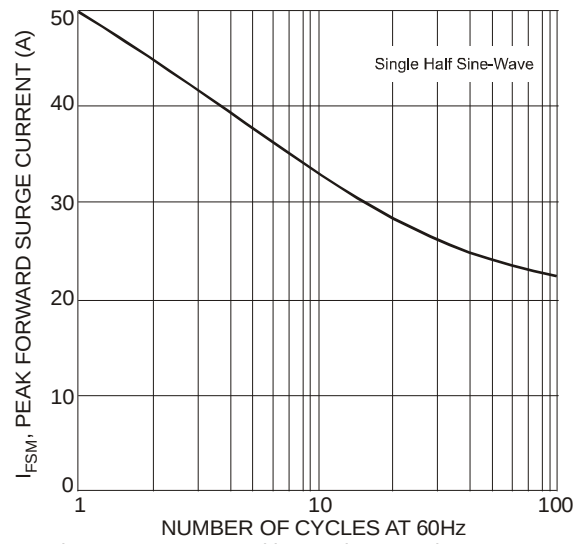
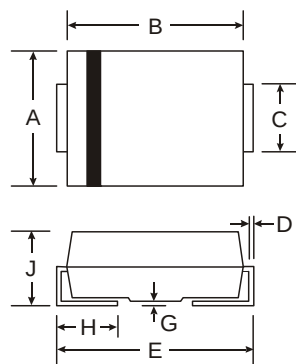


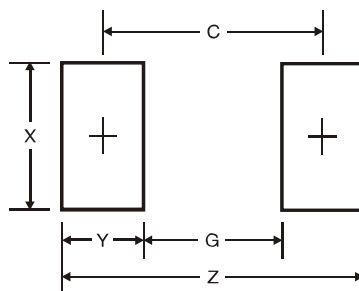
Fig. 4 Max Non-Repetitive Peak Forward Surge Current

Package Outline Dimensions



SMB		
Dim	Min	Max
A	3.30	3.94
B	4.06	4.57
C	1.96	2.21
D	0.15	0.31
E	5.00	5.59
G	0.05	0.20
H	0.76	1.52
J	2.00	2.50
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
Z	6.8
G	1.8
X	2.3
Y	2.5
C	4.3

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